

Features

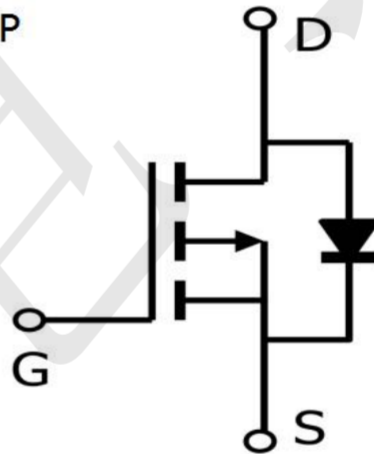
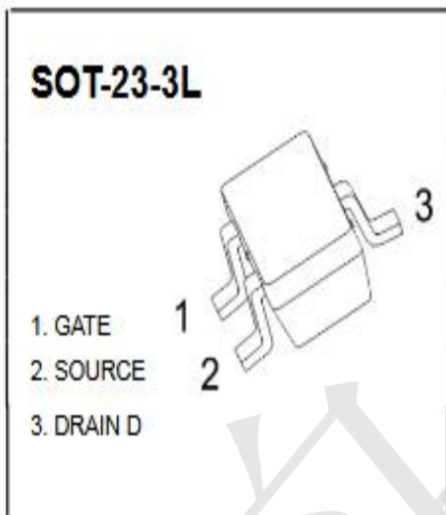
- -20 V -3A **RDS(on)MAX**
- 90mΩ -4.5V
- 115mΩ@-2.5V
- SOT23-3L

Applications

- Load Switch for Portable Devices
- DC/DC Converter

Ordering Information

Part Number	Qty per Reel	Reel Size
A02301	3000	7"

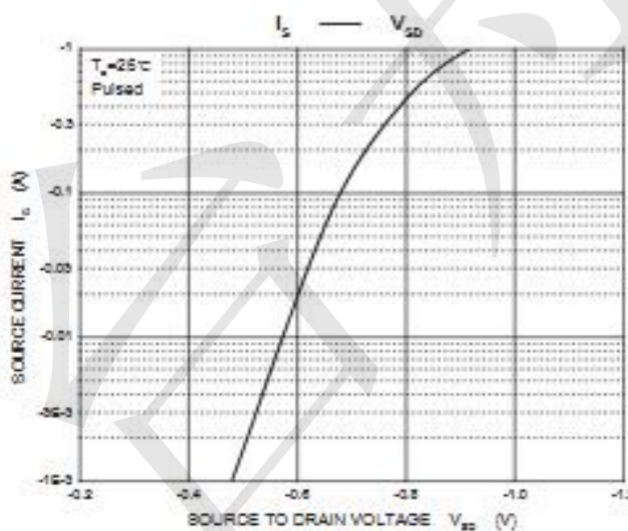
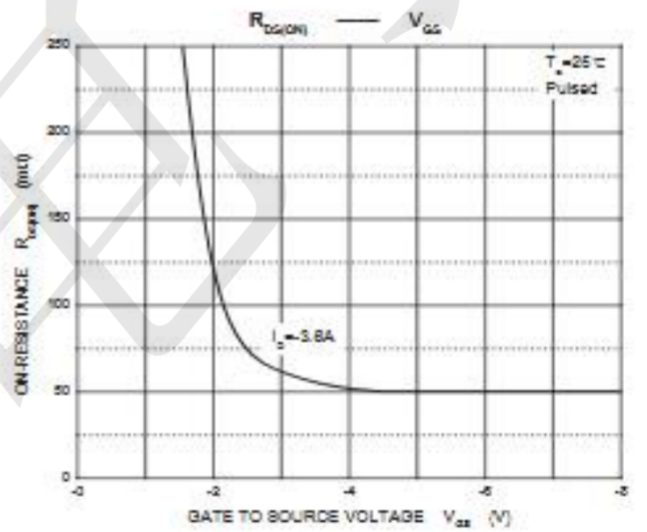
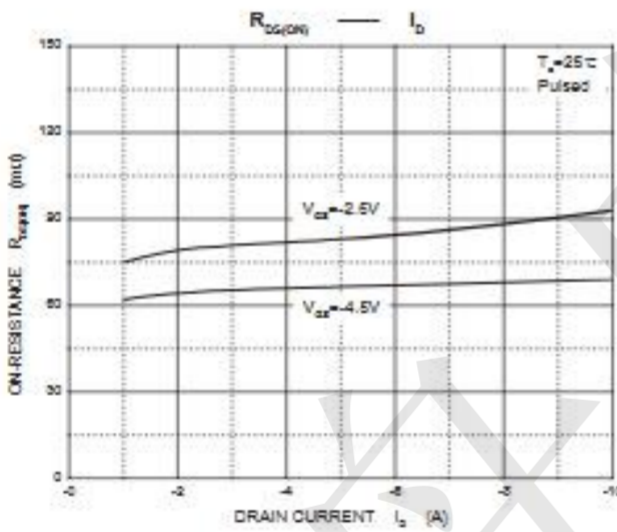
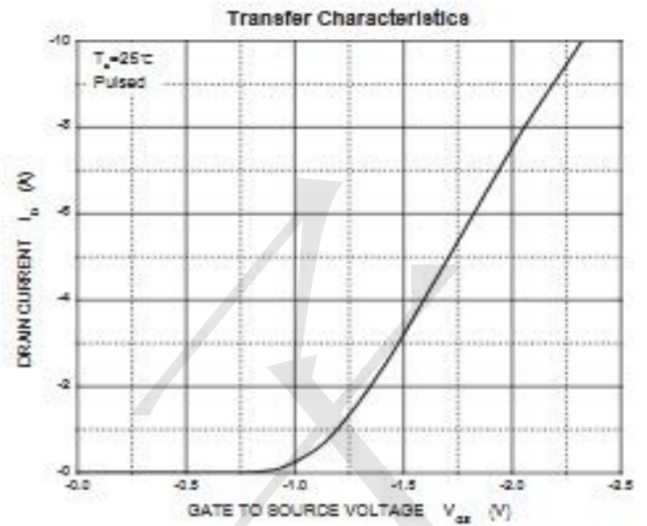
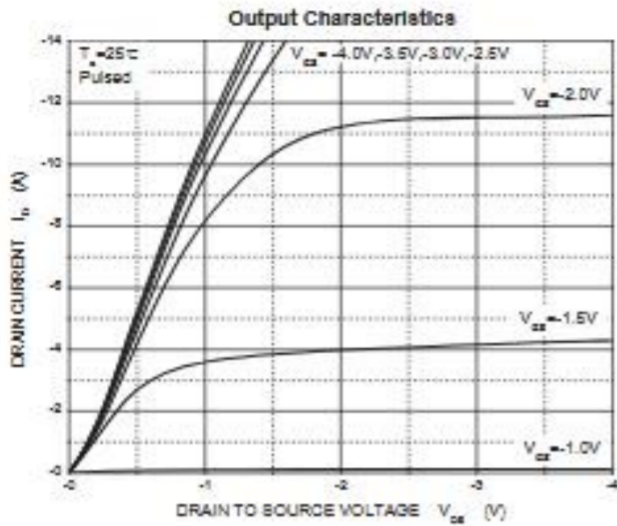


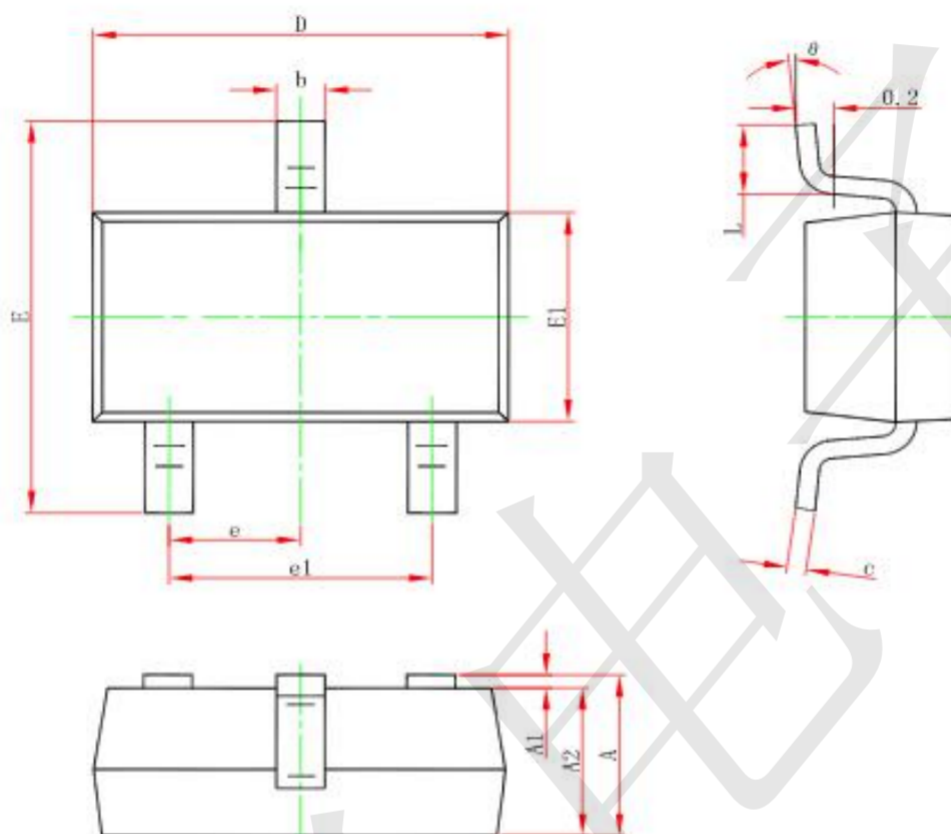
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-20	V
Gate-Source Voltage	V _{GS}	±12	
Continuous Drain Current	I _D	-3	A
Pulsed Diode Current	I _{DM}	-15	
Continuous Source-Drain Current(Diode Conduction)	I _S	-0.8	
Power Dissipation	PD	1.25	W
Thermal Resistance from Junction to Ambient (t≤5s)	R _{θJA}	150	°C/W
Operating Junction	T _J	150	°C
Storage Temperature	T _{STG}	-55~+150	°C

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Drain-source breakdown voltage	V(BR)DSS	VGS = 0V, ID = -250 μ A	-20			V
Gate-source threshold voltage	VGS(th)	VDS = VGS, ID = -250 μ A	-0.4		-1.	V
Gate-source leakage	IGSS	VDS = 0V, VGS = \pm 12V			\pm 100	nA
Zero gate voltage drain current	IDSS	VDS = -20V, VGS = 0V			-1	μ A
Drain-source on-state resistance ^a	RDS(on)	VGS = -4.5V, ID = -3A		66	90	m Ω
		VGS = -2.5V, ID = -2A		83	115	m Ω
Forward transconductance ^a	gfs	VDS = -4.5V, ID = -3A		4		S
Diode forward voltage	VSD	IS = -1A, VGS = 0V		-0.8	-1.3	V
Dynamic						
Input capacitance	Ciss	VDS = -16V, VGS = 0V, f = 1MHz		589		pF
Output capacitance	Coss			92		pF
Reverse transfer capacitance ^b	Crss			68		pF
Total gate charge	Qg	VDS = -16V, VGS = -4.5V, ID = -3A		5.5	10	nC
Gate-source charge	Qgs			0.8		nC
Gate-drain charge	Qgd			1.3		nC
Gate resistance	Rg	f = 1MHz		6		Ω
Switching^b						
Turn-on delay time	td(on)	VDD = -10V RL = 6 Ω , ID \approx -3A, VGEN = -4.5V, Rg = 6 Ω		10	20	ns
Rise time	tr			35	60	ns
Turn-off delay time	td(off)			30	50	ns
Fall time	tf			10	20	ns
Drain-source body diode characteristics						
Continuous Source-Drain Diode Current	IS	Tc = 25 $^\circ$ C			-1.3	A
Pulsed Diode forward Current	ISM				-20	A



SOT-23-3L PACKAGE OUTLINE DIMENSIONS


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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